## SYSTEM AND METHOD FOR PROVIDING A SELF HEATING ADJUSTABLE Tisi2 RESISTOR

## ABSTRACT OF THE DISCLOSURE

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A system and method is disclosed for providing a self heating adjustable titanium disilicon (TiSi<sub>2</sub>) resistor. A triangularly shaped layer of polysilicon is placed a layer of insulation material. A layer of titanium is applied over the polysilicon and heated to form a layer of C49 type of TiSi<sub>2</sub>. A current is then applied to the small end of the triangularly shaped layer of C49 TiSi<sub>2</sub>. The current generates heat in a high resistance portion of the triangularly shaped layer of C49 TiSi<sub>2</sub> and converts a portion of the C49 TiSi<sub>2</sub> to C54 TiSi<sub>2</sub>. The lower resistance of the C54 TiSi<sub>2</sub> decreases the effective resistance of the resistor. A desired value of resistance may be selected by adjusting the magnitude of the applied current.